

#### Features

#### Applications

Low-level light measurement

Analytical instrument

High sensitivity at short wavelength

- QE: 90% (λ=420 nm)
- Low noise
- High gain

# Structure / Absolute maximum ratings

			Effective.	Effective	Absolute maximum ratings			
Type no.	Dimensional outline /Window material*1	Package	Effective photosensitive area size <sup>*2</sup>	Effective photosensitive area	Operating temperature* <sup>3</sup> Topr	Storage temperature <sup>*3</sup> Tstg (°C)		
			(mm)	(mm <sup>2</sup> )	(°Ċ)			
S16453-02K		TO-5	ф0.2	0.03		-55 to +100		
S16453-05K	①/K		ф0.5	0.19				
S16453-10K	γκ		φ1.0	0.78	-20 to +60			
S16453-20K			φ2.0	3.14	-20 10 +60			
S16453-30K	@/K	TO-8	ф3.0	7.0				
S16453-50K	@/K	10-0	φ5.0	19.6				

\*1: K: Borosilicate glass

\*2: Area in which a typical gain can be obtained

\*3: No dew condensation. When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

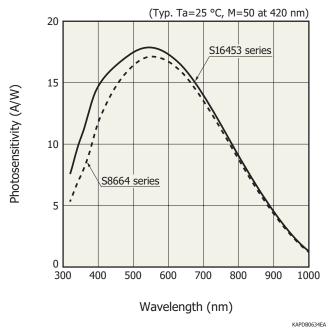
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

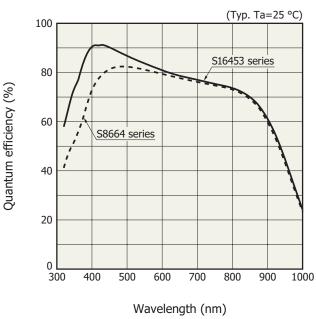
# Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Type no.	$\begin{array}{c c} \text{Spectral} \\ \text{response} \\ \text{range} \\ \lambda \\ \lambda p \end{array} \begin{array}{c} \text{Peak} \\ \text{sensitivity} \\ \text{wavelength}^{*4} \\ \lambda p \end{array}$	sensitivity	Quantum efficiency QE M=1	volt V	/BR coeffic	Temperature coefficient of VBR	curre	ark ent* <sup>4</sup> D	Cutoff frequency*4 fc	Terminal capacitance*4 Ct		Gain M λ=420 nm	
			-	λ=420 nm	Typ.	Max.		Typ.	Max.			Λ=420 mm	Λ=420 IIII
	(nm)	(nm)	(A/W)	(%)	(V)	(V)	(V/°C)	(nA)	(nA)	(MHz)	(pF)		
S16453-02K	320 to 5	550	550 0.3	90	400	500	0.78	0.1	1	700	0.8	0.2	
S16453-05K								0.2	1.5	680	1.6		50
S16453-10K								0.3	3	470	4		
S16453-20K		550						0.6	6	165	11		
S16453-30K								1	15	75	22		
S16453-50K								3	35	30	55		

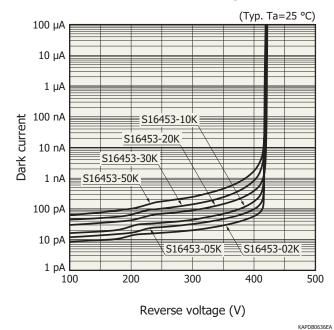
\*4: Values measured at a gain listed in the characteristics table





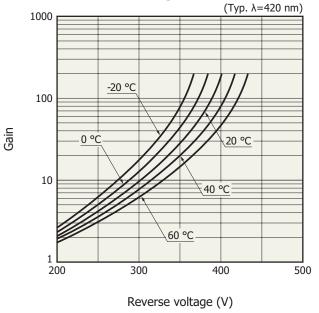


#### KAPDB0635EA



Dark current vs. reverse voltage

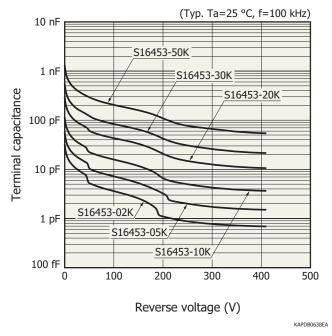
🗲 Gain vs. reverse voltage



KAPDB0637EA

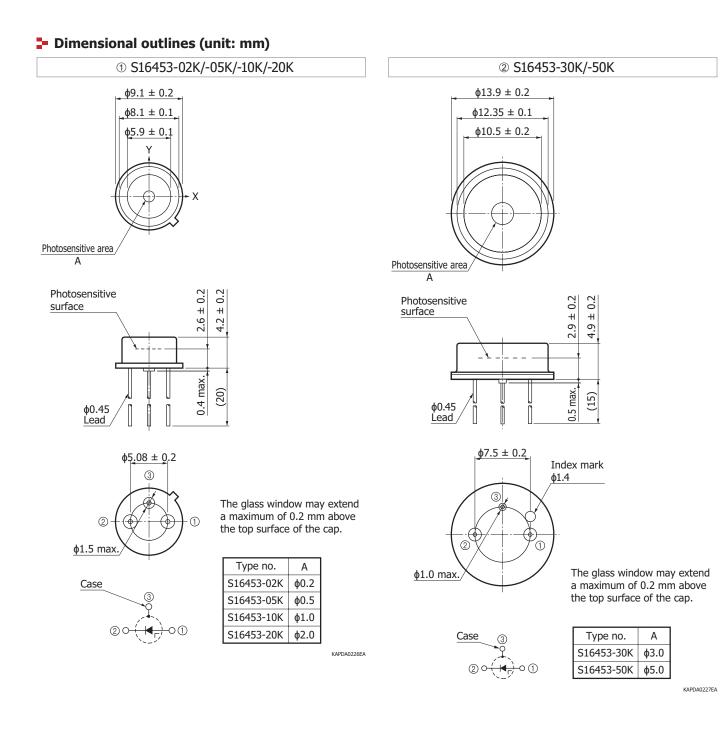
# Quantum efficiency vs. wavelength





# **Terminal capacitance vs. reverse voltage**







4

#### Recommended soldering conditions

Solder temperature: 260 °C (10 s or less, once) Solder the leads at a point at least 1 mm away from the package body.

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

Precautions

- Disclaimer
- · Metal, ceramic, plastic package products
- Technical note
- · Si APD

Information described in this material is current as of November 2023.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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